TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74VHC374F,TC74VHC374FT,TC74VHC374FK

#### Octal D-Type Flip Flop with 3-State Output

The TC74VHC374 is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

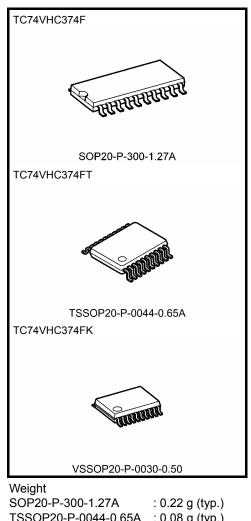
This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input  $(\overline{OE})$ .

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### Features

- High speed:  $f_{max} = 185 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2 to 5.5 V
- Low noise:  $V_{OLP} = 0.9 V (max)$
- Pin and function compatible with 74ALS374



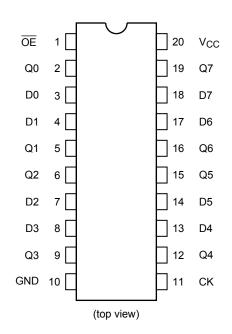
 SOP20-P-300-1.27A
 : 0.22 g (typ.)

 TSSOP20-P-0044-0.65A
 : 0.08 g (typ.)

 VSSOP20-P-0030-0.50
 : 0.03 g (typ.)

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## **Pin Assignment**



## **IEC Logic Symbol**

0E <u>(1)</u> CK <u>(11)</u>	EN > C1			
on	<u>ر</u> ،			
D0 <u>(3)</u>	1D	⊳	▽	<u>(2)</u> Q0
D1 <u>(4)</u>				<u>(5)</u> Q1
D2 <u>(7)</u>				<u>(6)</u> Q2
D3 <u>(8)</u>				<u>(9)</u> Q3
D4 (13)				<u>(12)</u> Q4
D5 <u>(14)</u>				<u>(15)</u> Q5
D6 (17)				<u>(16)</u> Q6
D7 <u>(18)</u>				<u>(19)</u> Q7

### Truth Table

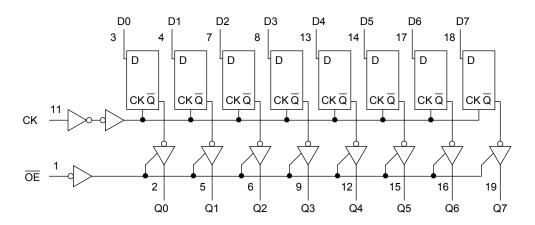
	Inputs	Output			
ŌĒ	СК	D	Output		
Н	Х	Х	Z		
L		Х	Qn		
L		L	L		
L		Н	Н		

X: Don't care

Z: High impedance

Qn: No change

## System Diagram



#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIК	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	ICC	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V
Input rise and fall time	uvuv	0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)	115/ V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Characteristics Symbol Test Conditi		Test Condition		٦	Га = 25°(	0	Ta −40 to	Unit	
	,			$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
High-level input VIH —		2.0 3.0 to	1.50	_	_	1.50	_	v		
voltage	- 111			5.5	V <sub>CC</sub> × 0.7	_	—	V <sub>CC</sub> × 0.7	—	
Low-level input				2.0	_	_	0.50	_	0.50	
voltage	V <sub>IL</sub>			3.0 to 5.5	—		V <sub>CC</sub> × 0.3	—	V <sub>CC</sub> × 0.3	V
				2.0	1.9	2.0	—	1.9	_	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = −50 µA	3.0	2.9	3.0	—	2.9	—	
High-level output voltage	V <sub>OH</sub>			4.5	4.4	4.5	—	4.4	—	V
J. J			I <sub>OH</sub> = −4 mA	3.0	2.58	-	_	2.48	-	
			I <sub>OH</sub> = −8 mA	4.5	3.94	—	—	3.80	—	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0	—	0.0	0.1	—	0.1	.1
			l <sub>OL</sub> = 50 μA	3.0 —	0.0	0.1	—	0.1		
Low-level output voltage	V <sub>OL</sub>			4.5	—	0.0	0.1	—	0.1	V
Ū.			I <sub>OL</sub> = 4 mA	3.0	—		0.36	—	0.44	
			I <sub>OL</sub> = 8 mA	4.5	—	-	0.36	—	0.44	
3-state output off-state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_	-	±0.25	_	±2.50	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μA
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> of	GND	5.5	_	_	4.0	_	40.0	μA

## Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Test Condition			Ta = 25°C		Ta = −40 to 85°C	Unit	
			V <sub>CC</sub> (V)	Тур.	Limit	Limit		
Minimum pulse width	t <sub>w (H)</sub>		3.3 ± 0.3	_	5.0	5.5	ns	
(CK)	t <sub>w (L)</sub>	—	5.0 ± 0.5	—	5.0	5.0		
Minimum act un timo	+	_	3.3 ± 0.3	-	4.5	4.5	20	
Minimum set-up time	ts		$5.0 \pm 0.5$	—	3.0	3.0	ns	
Minimum hold time	<b>t</b> .		3.3 ± 0.3	_	2.0	2.0	20	
Minimum hold time	t <sub>h</sub>	—	$5.0 \pm 0.5$	—	2.0	2.0	ns	

#### AC Characteristics (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Tes	st Condition	t Condition		Ta = 25°C			Ta = −40 to 85°C	
	,		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	8.1	12.7	1.0	15.0	
Propagation delay time	t <sub>pLH</sub>		$5.5 \pm 0.5$	50	_	10.6	16.2	1.0	18.5	ns
(CK-Q)	t <sub>pHL</sub>		5.0 ± 0.5	15	_	5.4	8.1	1.0	9.5	115
			$5.0 \pm 0.5$	50	_	6.9	10.1	1.0	11.5	
			3.3 ± 0.3	15	_	7.1	11.0	1.0	13.0	
3-state output enable time	t <sub>pZL</sub>	R <sub>L</sub> = 1 kΩ	5.5 ± 0.5	50	_	9.6	14.5	1.0	16.5	ns
	t <sub>pZH</sub>		5.0 ± 0.5	15	_	5.1	7.6	1.0	9.0	- 115
				50	_	6.6	9.6	1.0	11.0	
3-state output disable	t <sub>pLZ</sub>	R <sub>I</sub> = 1 kΩ	3.3 ± 0.3	50	_	10.2	14.0	1.0	16.0	ns
time	t <sub>pHZ</sub>	KL - 1 K22	5.0 ± 0.5	50	_	6.1	8.8	1.0	10.0	
		_	3.3 ± 0.3	15	80	130		70	_	MHz
Maximum clock				50	55	85		50	_	
frequency	f <sub>max</sub>		5.0 ± 0.5	15	130	185		110	_	
				50	85	120		75	_	
	t <sub>osLH</sub>	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	
Output to output skew	t <sub>osHL</sub>	(Note 1)	1) 5.0 ± 0.5	50	_	_	1.0	_	1.0	ns
Input capacitance	C <sub>IN</sub>		_			4	10	_	10	pF
Output capacitance	COUT		_			6		_	_	pF
Power dissipation capacitance	C <sub>PD</sub>			(Note 2)	_	32	_	—	_	pF

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|$ 

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per F/F)$ 

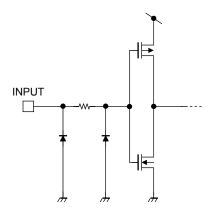
And the total  $C_{PD}$  when n pcs. of latch operate can be gained by the following equation:

C<sub>PD</sub> (total) = 20 + 12·n

## Noise Characteristics (input: tr = tf = 3 ns)

Characteristics	Symbol	Test Condition		Ta =	- Unit	
	Symbol		$V_{CC}(V)$	Тур.	Max	Offic
Quiet output maximum dynamic $V_{OL}$	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic $V_{OL}$	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage	VIHD	C <sub>L</sub> = 50 pF	5.0		3.5	V
Maximum low level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0		1.5	V

## Input Equivalent Circuit

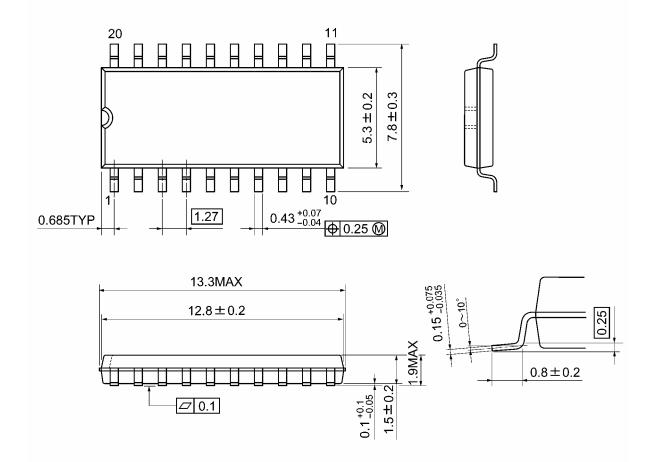




#### **Package Dimensions**

SOP20-P-300-1.27A

Unit: mm



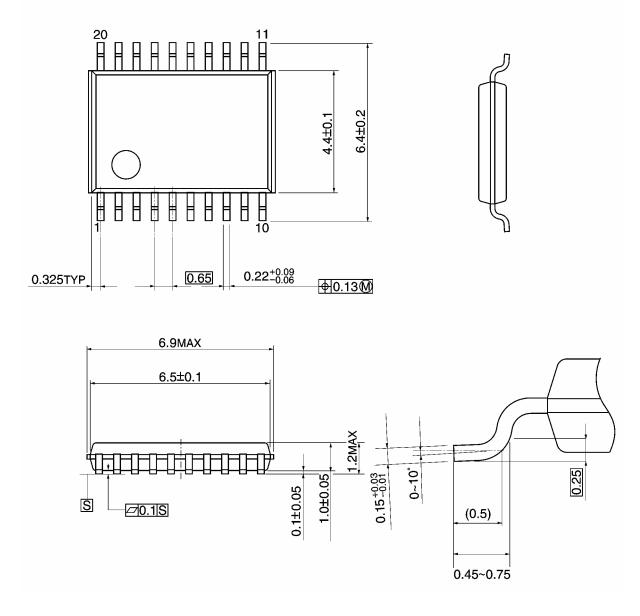
Weight: 0.22 g (typ.)

# **TOSHIBA**

#### **Package Dimensions**

TSSOP20-P-0044-0.65A

Unit: mm



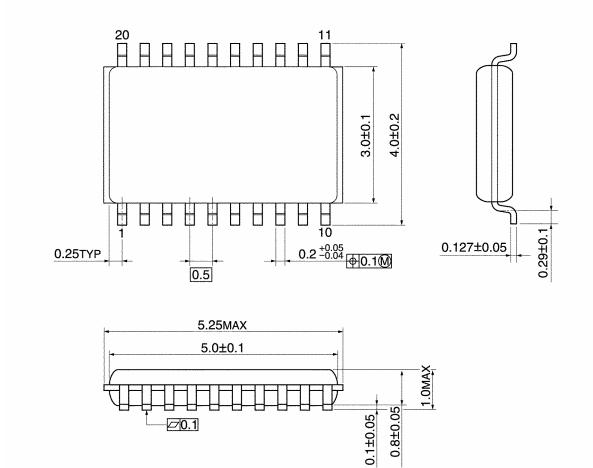
Weight: 0.08 g (typ.)

TOSHIBA

#### **Package Dimensions**

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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